Application No.: 10/029,204

Atty Docket No.: Q63141

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the

application:

LISTING OF CLAIMS:

Claim 1. (currently amended): A magnetic recording medium comprising, in

sequence, on a nonmagnetic substrate:

at least one soft magnetic underlayer;

an orientation control layer to control the orientation of the layer immediately thereabove;

and

a perpendicular magnetic layer having an axis of easy magnetization which is oriented

mainly perpendicularly to the nonmagnetic substrate,

wherein said soft magnetic underlayer has a multilayer structure consisting of having a

plurality of soft magnetic layers comprising a soft magnetic material, and one or more separation

layers interposed between said soft magnetic layers,

at least one of said soft magnetic layers comprises a material with a structure having no

magnetic domain walls,

a direction of magnetization of an upper soft magnetic layer is different from a direction

of magnetization of a lower soft magnetic layer, and

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the direction of the magnetization of said soft magnetic layer is along the radius of said nonmagnetic substrate and is oriented towards the periphery of the substrate or towards the center of said nonmagnetic substrate.

- Claim 2. (previously presented): A magnetic recording medium according to claim 1, wherein the material with a structure having no magnetic domain walls is comprises one selected from FeAlSi, FeTaN, FeTaC, FeC, FeAlSi alloys, FeTaN alloys, and FeTaC alloys.
- Claim 3. (previously presented): A magnetic recording medium according to claim 1, wherein the separation layer comprises 50 at. % or more of one or more of the elements Ru, Rh, Re, Ir, and Cu.
- Claim 4. (previously presented): A magnetic recording medium according to claim 1, wherein the separation layer is constituted of a soft magnetic material that is different from the material constituting the soft magnetic layers between which the separation layer is interposed.
- Claim 5. (previously presented): A magnetic recording medium according to claim 1, wherein the product $Bs \cdot t \ (T \cdot nm)$ of the saturation magnetic flux density per layer $Bs \ (T)$ of the soft magnetic layer and the thickness of the soft magnetic layer $t \ (nm)$, is $3 \ T \cdot nm$ or more for each of the soft magnetic layers.
- Claim 6. (previously presented): A magnetic recording medium according to claim 1, wherein the magnetic flux density of the soft magnetic layer is 0.4 T or more.
- Claim 7. (previously presented): A magnetic recording medium according to claim 1, wherein the thickness of the soft magnetic underlayer is 40 nm or more.

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Claim 8. (original): A magnetic recording medium according to claim 1, wherein the thickness of the separation layer is in the range from 0.1 nm to 5 nm.

Claim 9. (canceled).

Claim 10. (previously presented): A magnetic recording medium according to claim 1, wherein among sets of an upper and a lower soft magnetic layers between which a separation layer is interposed, at least one set has directions of magnetization which are antiparallel.

Claim 11. (canceled).

Claim 12. (previously presented): A magnetic recording medium according to claim 1, wherein a hard magnetic layer is formed between the nonmagnetic substrate and the soft magnetic underlayer, and the magnetization of said hard magnetic layer is directed along the radius of the substrate and towards the periphery or the center of the substrate, and bonded with the magnetization of the soft magnetic layer which is the lowest layer of the soft magnetic underlayer.

Claim 13. (previously presented): A magnetic recording medium according to claim 1, wherein the lowest layer of the soft magnetic underlayer comprises a material of one selected from the group consisting of FeAlSi, FeTaN, FeTaC, FeAlSi alloys, FeTaN alloys, and FeTaC alloys.

Claim 14. (previously presented): A magnetic recording medium according to claim 1, wherein the top layer of the soft magnetic underlayer is a soft magnetic layer.

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Claim 15. (previously presented): A magnetic recording medium according to claim 1, wherein a part of the surface or all of the surface of the soft magnetic underlayer nearest the perpendicular magnetic layer is oxidized.

Claim 16. (currently amended): A method for producing a magnetic recording medium on a nonmagnetic substrate, comprising the steps of:

forming at least one soft magnetic underlayer,

forming an orientation control layer for controlling the orientation of the layer immediately above, and

forming a perpendicular magnetic layer having an axis of easy magnetization which is oriented mainly perpendicularly to the substrate,

wherein the soft magnetic underlayer having a multilayer structure consisting of has a plurality of soft magnetic layers comprising a soft magnetic material, and one or more separation layers interposed between said soft magnetic layers,

one or more of the soft magnetic layers comprises a material with a structure having no magnetic domain walls, and

a magnetization of said soft magnetic layer is directed along the radius of said nonmagnetic substrate towards the periphery or the center of said nonmagnetic substrate.

Claim 17. (previously presented): A method for producing a magnetic recording medium according to claim 16, wherein the material with a structure having no magnetic domain

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walls comprises one selected from the group consisting of FeAlSi, FeTaN, FeTaC, FeC, FeAlSi alloys, FeTaN alloys, and FeTaC alloys.

Claim 18. (canceled).

Claim 19. (previously presented): A method for producing a magnetic recording medium according to claim 16 wherein a treatment for oxidizing the surface of the soft magnetic underlayer is included.

Claim 20. (currently amended): A magnetic recording and reproducing device comprising:

a magnetic recording medium having at least nonmagnetic substrate, a soft magnetic underlayer, an orientation control layer to control the orientation of the layer immediately above it, and a perpendicular magnetic layer having an axis of easy magnetization which is oriented mainly perpendicularly to the nonmagnetic substrate,

and a magnetic head for carrying out recording and reproducing of the information to and from the magnetic recording medium,

wherein the soft magnetic underlayer of the magnetic recording medium has a multilayer structure consisting of having a plurality of soft magnetic layers comprising a soft magnetic material, and one or more separation layers interposed between the soft magnetic layers,

one or more of the soft magnetic layers comprises a material with a structure having no magnetic domain walls, and

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a magnetization of said soft magnetic layer is directed along the radius of said nonmagnetic substrate towards the periphery or the center of said nonmagnetic structure.

Claim 21. (currently amended): A magnetic recording and reproducing device according to claim 20, wherein the material with a structure having no magnetic domain walls comprises one selected from the group consisting of FeAlSi, FeTaN, FeTaC, FeC, FeAlSi type alloys, FeTaN type-alloys, and FeTaC type-alloys.

Claim 22. (New) A magnetic recording medium according to claim 1, wherein the thickness of the orientation control layer is in the range from 8 nm to 50 nm.

Claim 23. (New) A magnetic recording medium according to claim 1, wherein the material of the orientation control layer comprises one selected from NiAl, FeAl, CoFe, CoZr, AlCo, Zr, Y, Zn, Ru, Re, Hf, Ni, Pd, Pt, Al, Cu, Ag, Ir, Si, Co, and Si or Co alloys.

Claim 24. (New) A method for producing a magnetic recording medium according to claim 16, wherein the thickness of the orientation control layer is in the range from 8 nm to 50 nm.

Claim 25. (New) A method for producing a magnetic recording medium according to claim 16, wherein the material of the orientation control layer comprises one selected from NiAl, FeAl, CoFe, CoZr, AlCo, Zr, Y, Zn, Ru, Re, Hf, Ni, Pd, Pt, Al, Cu, Ag, Ir, Si, Co, and Si or Co alloys.